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501.39868400 Faruson

IN THE INITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

SAITO et al.

Serial No.:

09/850,162

Filed:

May 8, 2001

For:

A SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE AND A

METHOD OF MANUFACTURING THE SAME

Group:

2812

Examiner:

L. Gurley

## AMENDMENT

Assistant Commissioner for Patents Washington, D.C. 20231 December 26, 2001

Sir:

In response to the Office Action dated October 26, 2001, the period of response for which extension is requested by the attached Petition for Extension of Time, please amend the companion of the above-identified application as follows:

## In the Claims:

## Please amend claims 6 and 7 as follows:

6. (Amended) A method for manufacturing a semiconductor integrated circuit device according to Claim 1, 4 or 5 further comprising the steps of:

partly removing said second insulating film defined in Claim 1, said third insulating film defined in Claim 4 or said